

DO-214AA (SMB)

### FEATURES

- Glass passivated chip junction
- Ideal for automated placement
- Ultrafast recovery times for high efficiency
- Low forward voltage, low power loss
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC



**RoHS**  
COMPLIANT

### TYPICAL APPLICATIONS

For use in high frequency rectification and freewheeling application in switching mode converter and inverter for both consumer and automotive.

### MECHANICAL DATA

**Case:** DO-214AA (SMB)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS compliant, commercial grade

Base P/NHE3 - RoHS compliant, AEC-Q101 qualified

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

**Polarity:** Color band denotes cathode end

| PRIMARY CHARACTERISTICS |                     |
|-------------------------|---------------------|
| $I_{F(AV)}$             | 2.0 A               |
| $V_{RRM}$               | 100 V, 150 V, 200 V |
| $t_{rr}$                | 25 ns               |
| $V_F$                   | 0.93 V              |
| $T_J \text{ max.}$      | 175 °C              |

| MAXIMUM RATINGS ( $T_A = 25\text{ °C}$ unless otherwise noted)                     |                |               |       |       |      |
|------------------------------------------------------------------------------------|----------------|---------------|-------|-------|------|
| PARAMETER                                                                          | SYMBOL         | ESH2B         | ESH2C | ESH2D | UNIT |
| Device marking code                                                                |                | EHB           | EHC   | EHD   |      |
| Maximum repetitive peak reverse voltage                                            | $V_{RRM}$      | 100           | 150   | 200   | V    |
| Maximum RMS voltage                                                                | $V_{RMS}$      | 70            | 105   | 140   | V    |
| Maximum DC blocking voltage                                                        | $V_{DC}$       | 100           | 150   | 200   | V    |
| Maximum average forward rectified current (fig. 1)                                 | $I_{F(AV)}$    | 2.0           |       |       | A    |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load | $I_{FSM}$      | 60            |       |       | A    |
| Operating junction and storage temperature range                                   | $T_J, T_{STG}$ | - 55 to + 175 |       |       | °C   |



| ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted) |                                                                                                      |                         |                               |       |      |
|----------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------|-------------------------|-------------------------------|-------|------|
| PARAMETER                                                                  | TEST CONDITIONS                                                                                      |                         | SYMBOL                        | VALUE | UNIT |
| Maximum instantaneous forward voltage                                      | I <sub>F</sub> = 2 A                                                                                 |                         | V <sub>F</sub> <sup>(1)</sup> | 0.93  | V    |
| Maximum DC reverse current at rated DC blocking voltage                    |                                                                                                      | T <sub>A</sub> = 25 °C  | I <sub>R</sub>                | 2.0   | μA   |
|                                                                            |                                                                                                      | T <sub>A</sub> = 125 °C |                               | 50    |      |
| Maximum reverse recovery time                                              | I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1 A, I <sub>rr</sub> = 0.25 A                               |                         | t <sub>rr</sub>               | 25    | ns   |
| Typical reverse recovery time                                              | I <sub>F</sub> = 2 A, V <sub>R</sub> = 30 V, dI/dt = 50 A/μs, I <sub>rr</sub> = 10 % I <sub>RM</sub> | T <sub>J</sub> = 25 °C  | t <sub>rr</sub>               | 35    | ns   |
|                                                                            |                                                                                                      | T <sub>J</sub> = 100 °C |                               | 55    |      |
| Typical stored charge                                                      | I <sub>F</sub> = 2 A, V <sub>R</sub> = 30 V, dI/dt = 50 A/μs, I <sub>rr</sub> = 10 % I <sub>RM</sub> | T <sub>J</sub> = 25 °C  | Q <sub>rr</sub>               | 20    | nC   |
|                                                                            |                                                                                                      | T <sub>J</sub> = 100 °C |                               | 35    |      |
| Typical junction capacitance                                               | 4.0 V, 1 MHz                                                                                         |                         | C <sub>J</sub>                | 30    | pF   |

**Note**(1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle

| THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted) |                                 |       |       |       |      |
|-------------------------------------------------------------------------|---------------------------------|-------|-------|-------|------|
| PARAMETER                                                               | SYMBOL                          | ESH2B | ESH2C | ESH2D | UNIT |
| Typical thermal resistance                                              | R <sub>θJA</sub> <sup>(1)</sup> | 65    |       |       | °C/W |
|                                                                         | R <sub>θJL</sub> <sup>(1)</sup> | 20    |       |       |      |

**Note**

(1) Units mounted on P.C.B. with 8.0 mm x 8.0 mm land areas

| ORDERING INFORMATION (Example) |                 |                        |               |                                    |
|--------------------------------|-----------------|------------------------|---------------|------------------------------------|
| PREFERRED P/N                  | UNIT WEIGHT (g) | PREFERRED PACKAGE CODE | BASE QUANTITY | DELIVERY MODE                      |
| ESH2D-E3/52T                   | 0.096           | 52T                    | 750           | 7" diameter plastic tape and reel  |
| ESH2D-E3/5BT                   | 0.096           | 5BT                    | 3200          | 13" diameter plastic tape and reel |
| ESH2DHE3/52T <sup>(1)</sup>    | 0.096           | 52T                    | 750           | 7" diameter plastic tape and reel  |
| ESH2DHE3/5BT <sup>(1)</sup>    | 0.096           | 5BT                    | 3200          | 13" diameter plastic tape and reel |

**Note**

(1) AEC-Q101 qualified

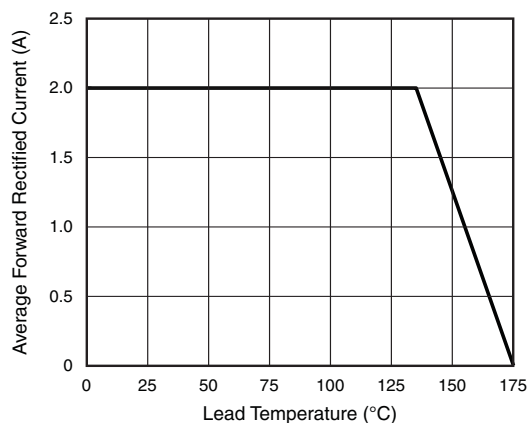
**RATINGS AND CHARACTERISTICS CURVES**( $T_A = 25\text{ }^{\circ}\text{C}$  unless otherwise noted)

Fig. 1 - Maximum Forward Current Derating Curve

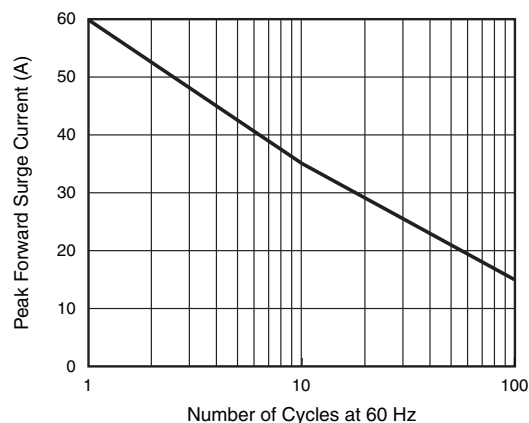


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

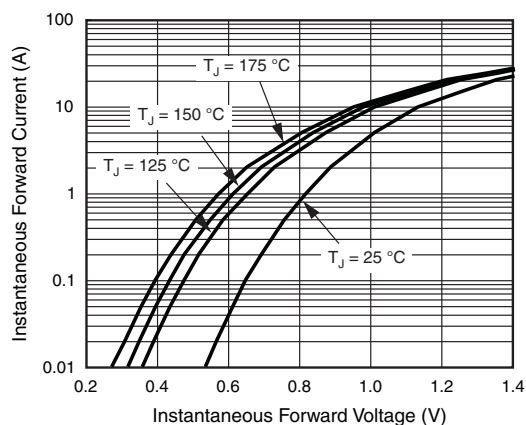


Fig. 3 - Typical Instantaneous Forward Characteristics

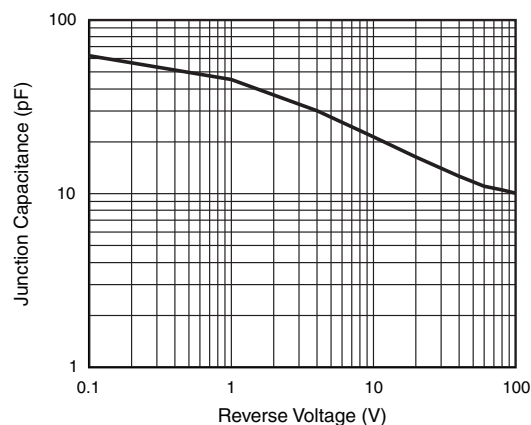


Fig. 5 - Typical Junction Capacitance

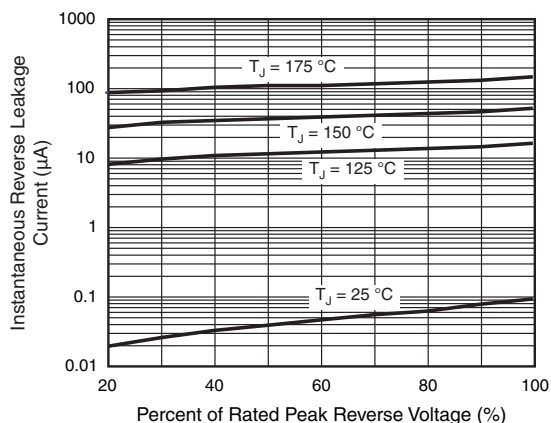


Fig. 4 - Typical Reverse Leakage Characteristics

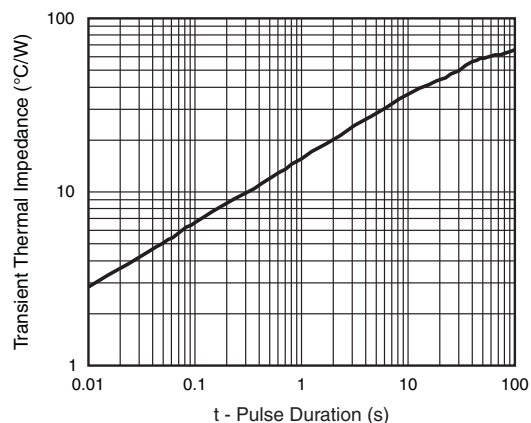
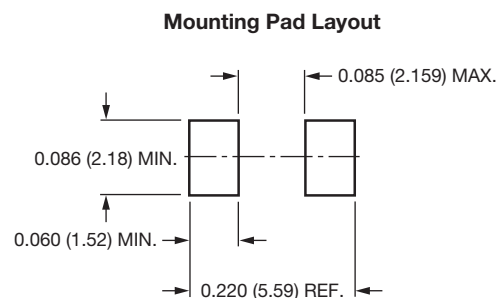
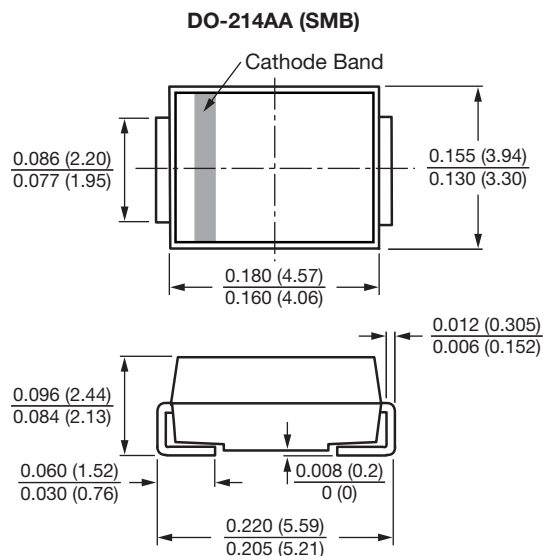


Fig. 6 - Typical Transient Thermal Impedance

## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





## Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

## Material Category Policy

**Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.**

**Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.**

## Данный компонент на территории Российской Федерации

**Вы можете приобрести в компании MosChip.**

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

### Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: [info@moschip.ru](mailto:info@moschip.ru)

Skype отдела продаж:

moschip.ru

moschip.ru\_4

moschip.ru\_6

moschip.ru\_9